



## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

Paton et al.

Title:

OFFSET SPACER SMOS PROCESS FOR FORMING

N-TYPE TRANSISTORS

Appl. No.:

10/619877

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Examiner:

Jeff B. Vockrodt

Art Unit:

2822

Confirmation No.:

7818

## AMENDMENT AND REPLY UNDER 37 CFR 1.111

Mail Stop NON-FEE AMENDMENT Commissioner for Patents PO Box 1450 Alexandria, Virginia 22313-1450

This communication is responsive to the Non-Final Office Action dated March 29, 2004, concerning the above-referenced patent application.

Amendments to the Specification begin on page 2 of this document.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this document.

Remarks/Arguments begin on page 7 of this document.

Please amend the application as follows: